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Power Schottky rectifier

Features

- Negligible switching losses
- Low forward voltage drop
- Surface mount miniature package
- Avalanche capability specified
- ECOPACK2[®] compliant component (SMB flat)

Description

Axial and surface mount power Schottky rectifiers suited to switched mode power supplies and high frequency DC to DC converters.

Packaged in SMA, DO-41 and SMB flat this device is especially intended for use in low voltage, high frequency inverters and small battery chargers.

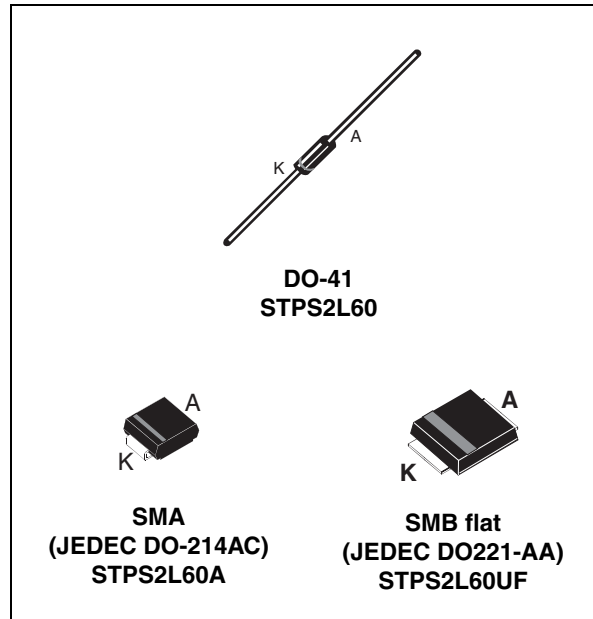


Table 1. Device summary

Symbol	Value
$I_{F(AV)}$	2 A
V_{RRM}	60 V
T_j (max)	150 °C
V_F (max)	0.55 V

1 Characteristics

Table 2. Absolute ratings (limiting values)

Symbol	Parameter		Value	Unit	
V _{RRM}	Repetitive peak reverse voltage		60	V	
I _{F(RMS)}	Forward rms voltage		10	A	
I _{F(AV)}	Average forward current	SMB flat	T _L = 130 °C δ = 0.5	2	A
		SMA	T _L = 115 °C δ = 0.5		
		DO-41	T _L = 110 °C δ = 0.5		
I _{FSM}	Surge non repetitive forward current		t _p = 10 ms sinusoidal	75	A
P _{ARM}	Repetitive peak avalanche power		t _p = 1 μs T _j = 25 °C	1600	W
T _{stg}	Storage temperature range		-65 to + 150	°C	
T _j	Maximum operating junction temperature ⁽¹⁾		150	°C	
dV/dt	Critical rate of rise of reverse voltage		10000	V/μs	

1. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Test conditions		Value	Unit
R _{th(j-l)}	Junction-lead	SMB flat	15	°C/W
		SMA	25	
		Lead length = 10 mm DO-41	30	

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}			100	μA
		T _j = 100 °C			2	10	mA
V _F ⁽¹⁾	Forward voltage drop	T _j = 25 °C	I _F = 2 A			0.60	V
		T _j = 125 °C			0.51	0.55	
		T _j = 25 °C	I _F = 4 A			0.77	
		T _j = 125 °C			0.62	0.67	

1. Pulse test: t_p = 380 μs, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.43 \times I_{F(AV)} + 0.06 I_{F(RMS)}^2$$

Figure 1. Average forward power dissipation versus average forward current

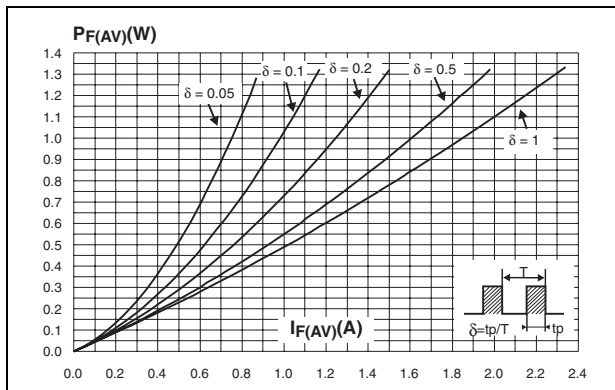


Figure 2. Average forward current versus ambient temperature (delta = 0.5) DO-41, SMA

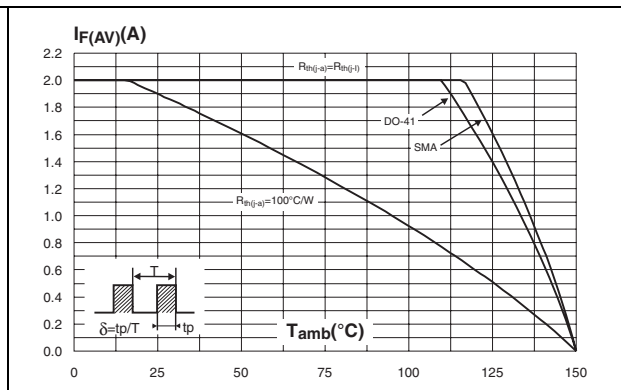


Figure 3. Average forward current versus ambient temperature (delta = 0.5) SMB flat

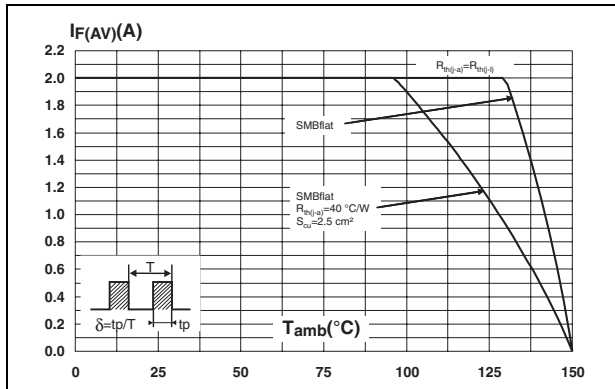


Figure 4. Normalized avalanche power derating versus pulse duration

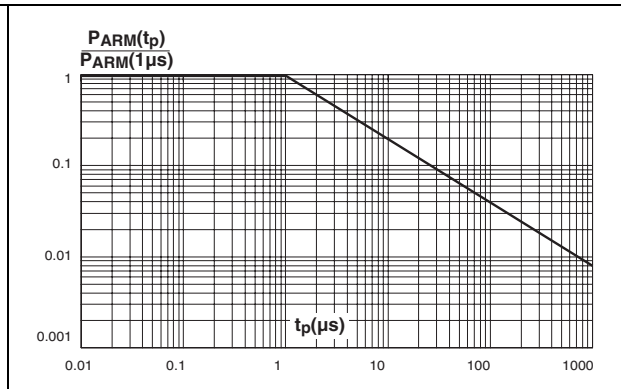


Figure 5. Normalized avalanche power derating versus junction temperature

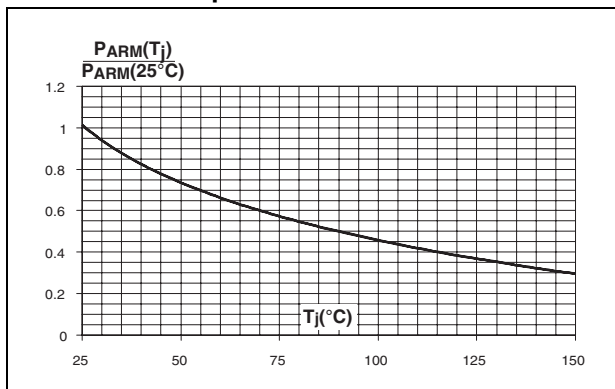


Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values) (SMA)

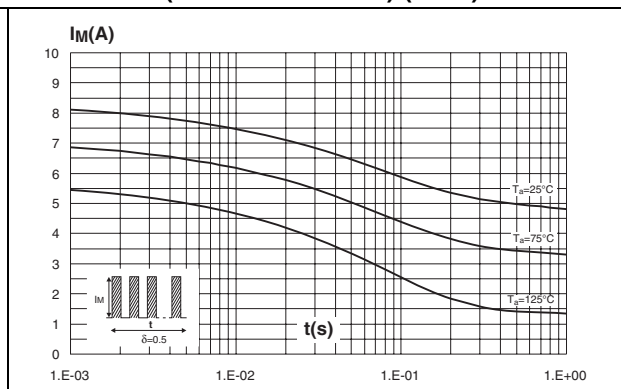


Figure 7. Non repetitive surge peak forward current versus overload duration (maximum values) (DO-41)

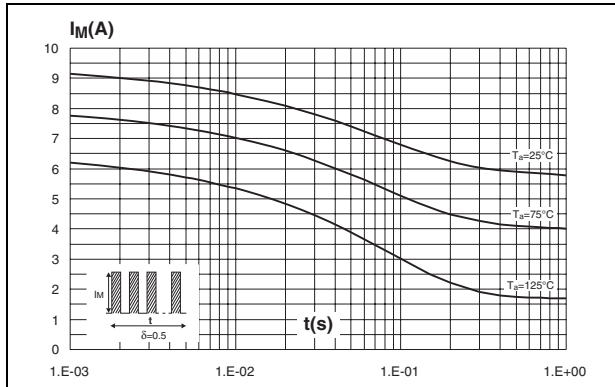


Figure 8. Non repetitive surge peak forward current versus overload duration (maximum values) (SMB flat)

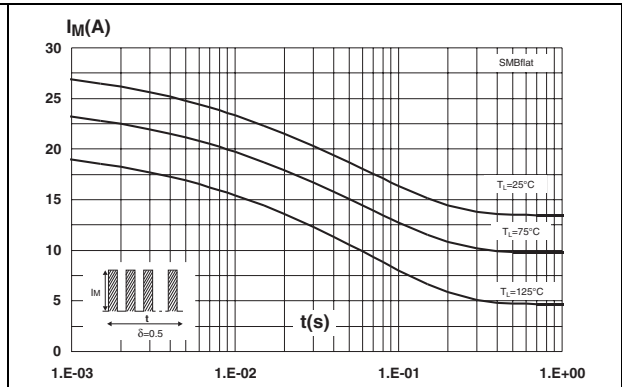


Figure 9. Relative variation of thermal impedance junction to ambient versus pulse duration (SMA)

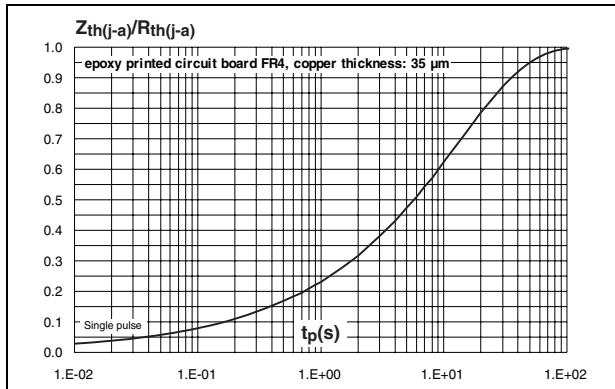


Figure 10. Relative variation of thermal impedance junction to ambient versus pulse duration (DO-41)

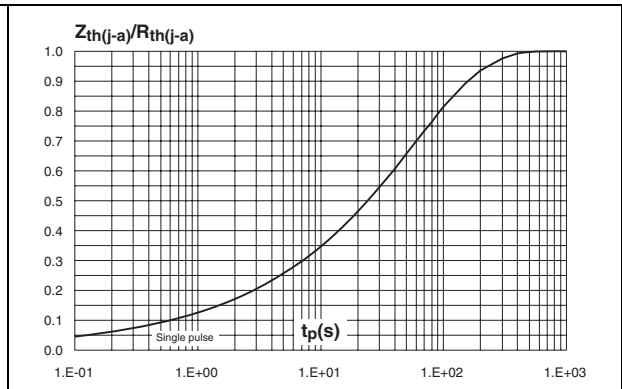


Figure 11. Relative variation of thermal impedance junction to lead versus pulse duration (SMB flat)

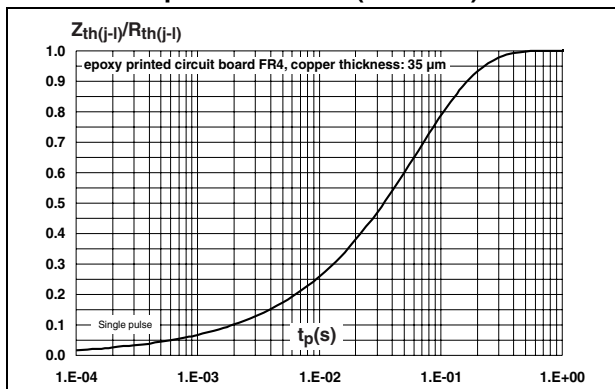


Figure 12. Reverse leakage current versus reverse voltage applied (typical values)

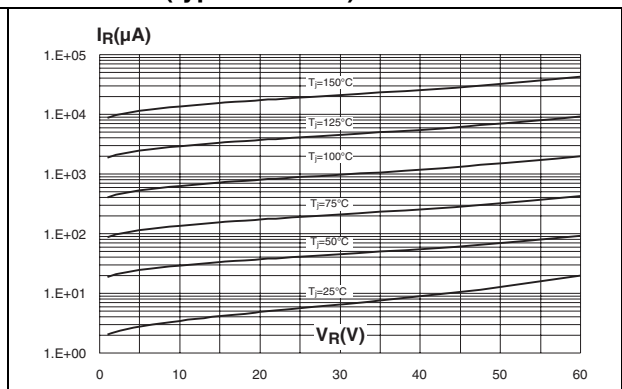


Figure 13. Junction capacitance versus reverse voltage applied (typical values)

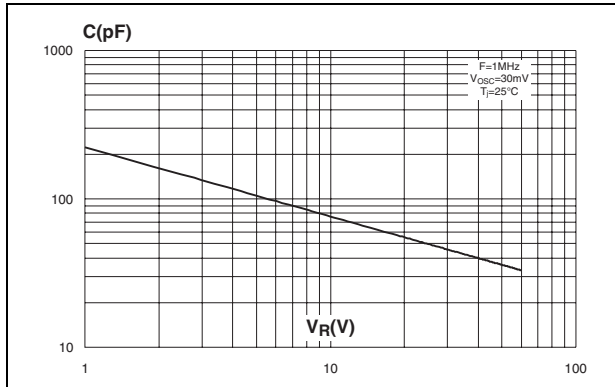


Figure 14. Forward voltage drop versus forward current (maximum values, low level)

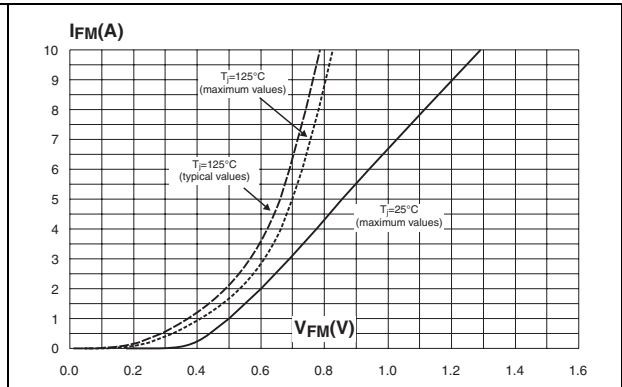


Figure 15. Thermal resistance junction to ambient versus copper surface under each lead (SMA and SMB flat)

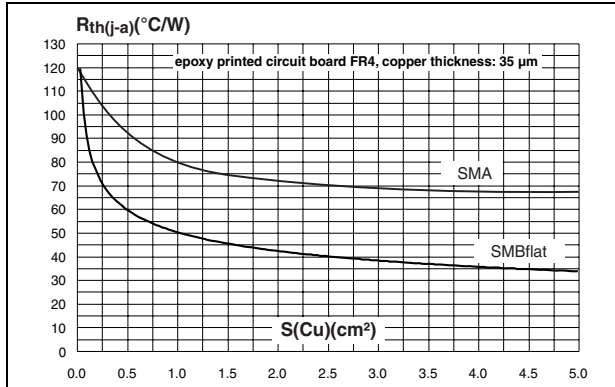
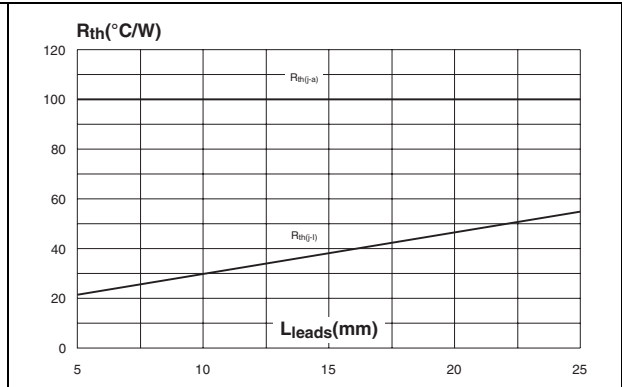


Figure 16. Thermal resistance versus lead length (DO-41)



2 Package information

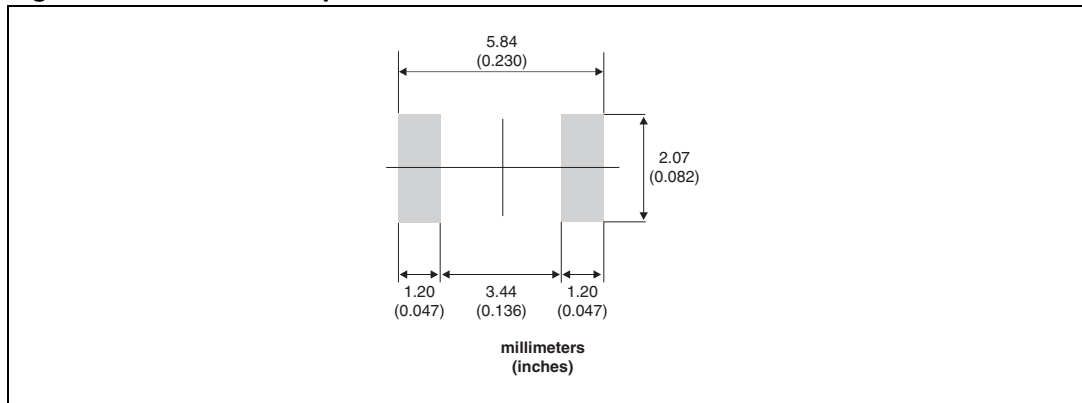
- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 5. SMB flat dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90		1.10	0.035		0.043
b	1.95		2.20	0.077		0.087
c	0.15		0.40	0.006		0.016
D	3.30		3.95	0.130		0.156
E	5.10		5.60	0.200		0.220
E1	4.05		4.60	0.189		0.181
L	0.75		1.50	0.029		0.059
L1		0.40			0.016	
L2		0.60			0.024	

Figure 17. SMB flat footprint dimensions



The footprint in [Figure 17](#) has been optimized for the SMB flat package. The footprint of the SMB package can be used instead.

Table 6. SMA dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.094
A2	0.05	0.20	0.002	0.008
b	1.25	1.65	0.049	0.065
c	0.15	0.40	0.006	0.016
D	2.25	2.90	0.089	0.114
E	4.80	5.35	0.189	0.211
E1	3.95	4.60	0.156	0.181
L	0.75	1.50	0.030	0.059

Figure 18. Footprint, dimensions in mm (inches)

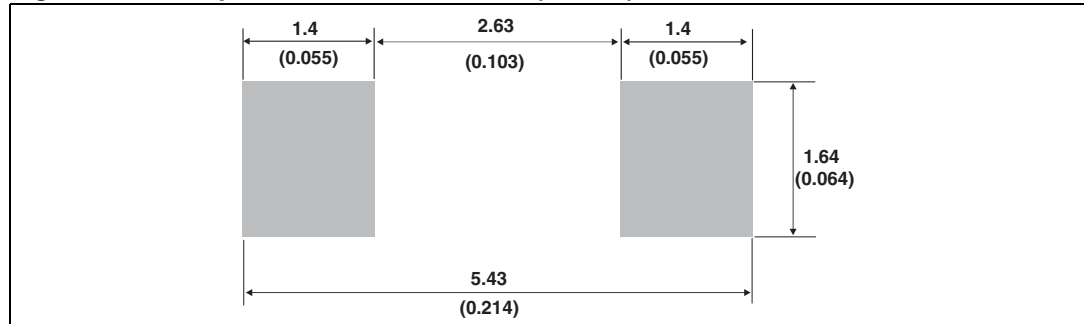


Table 7. DO-41 package dimensions

Ref	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.07	5.20	0.160	0.205
B	2.04	2.71	0.080	0.107
C	25.4		1	
D	0.71	0.86	0.028	0.034

3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS2L60A	S26	SMA	0.068 g	5000	Tape and reel
STPS2L60	STPS2L60	DO-41	0.34 g	2000	Ammopack
STPS2L60RL	STPS2L60	DO-41	0.34 g	5000	Tape and reel
STPS2L60UF	FG26	SMB flat	0.050 g	5000	Tape and reel

4 Revision history

Table 9. Document revision history

Date	Revision	Changes
Jul-2003	2A	Last update.
Aug-2004	3	SMA package dimensions update. Reference A1 max changed from 2.70 mm (0.106 inch) to 2.03 mm (0.080 inch).
18-Sep-2008	4	Reformatted to current standards. Added SMB flat package.
30-Sep-2009	5	Updated table 7 package dimensions.
23-Sep-2011	6	Updated SMA package information.

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